

features

- Static logic
- DC to 1 MHz operation
- Low power dissipation
- Push-pull output buffers
- TTL compatible

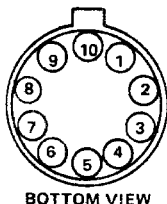
description

The TMS 3000 LR and TMS 3001 LR are dual static shift registers. Each device contains two dc-to-1-MHz shift registers with independent input and output terminals and common clocks and power. MOS thick-oxide technology is used to fabricate cross-coupled flip-flops for each register bit so that data can be stored indefinitely. Transistors in the device are P-channel enhancement-mode type. All input leads have zener network protection and all outputs contain low-output-impedance, non-inverting push-pull output buffers.

Two power supply levels and two clocks are required for operation with a third clock generated internally. Data is transferred into the register when the ϕ_1 clock is pulsed to logic 1. Data is shifted when the ϕ_1 clock is returned to logic 0 and the ϕ_2 clock is pulsed to logic 1. Output data appears on the logic 0 to logic 1 transition of the ϕ_2 clock. For long term storage, the ϕ_1 clock must be held at logic 0 and the ϕ_2 clock at logic 1.

mechanical data and pin configuration

The TMS 3000 LR and TMS 3001 LR are mounted in TO-100 packages. (See MOS/LSI packaging section.)



BOTTOM VIEW

PIN NO.	FUNCTION	PIN NO.	FUNCTION
1	Input 1	6	Clock ϕ_2
2	Output 1	7	V _{GG}
3	V _{DD}	8	Output 2
4	Clock ϕ_1	9	Input 2
5	GND (V _{SS})	10	No connection

logic definition

Negative logic is assumed

- Logic 1 = most negative voltage
- Logic 0 = most positive voltage.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage V _{DD} range (See Note 1)	-30 V to 0.3 V
Supply voltage V _{GG} range (See Note 1)	-30 V to 0.3 V
Phase one clock input voltage V ϕ_1 range (See Note 1)	-30 V to 0.3 V
Phase two clock input voltage V ϕ_2 range (See Note 1)	-30 V to 0.3 V
Data input voltage V _I range (See Note 1)	-30 V to 0.3 V
Power dissipation	450 mW
Operating free-air temperature range	-55°C to 85°C
Storage temperature range	-55°C to 150°C

NOTE 1: These voltage values are with respect to network ground terminal, V_{SS}.

TMS 3000 LR-DUAL 25-BIT STATIC SHIFT REGISTER

TMS 3001 LR-DUAL 32-BIT STATIC SHIFT REGISTER

recommended operating conditions

CHARACTERISTICS	MIN	NOM	MAX	UNITS
Supply voltage V_{DD}	-12	-14	-15	V
Supply voltage V_{GG}	-24	-28	-29	V
Logic 0 data input voltage $V_{i(0)}$ (See Note 2)	0.3	0	-2	V
Logic 1 data input voltage $V_{i(1)}$ (See Note 2)	-9.5	-14	-29	V
Width of data pulse, $t_p(\text{data})$ (See voltage waveforms)	0.4†			μs
Data setup time, t_{setup} (See voltage waveforms and Note 3)	100			ns
Data hold time, t_{hold} (See voltage waveforms and Note 4)	20			ns
Logic 0 clock input voltage $V_{\phi 0(\text{clock})}$ (See Notes 2 and 5)	0.3	0	-2	V
Logic 1 clock input voltage $V_{\phi 1(\text{clock})}$ (See Notes 2 and 5)	-24	-28	-29	V
Rise time of clock pulse, $t_r(\text{clock})$ (See voltage waveforms)	0		5	μs
Fall time of clock pulse, $t_f(\text{clock})$ (See voltage waveforms)			5	μs
ϕ_1 clock pulse width, $t_{p(\phi 1)}$ (See voltage waveforms)	0.3†		10†	μs
ϕ_2 clock pulse width, $t_{p(\phi 2)}$ (See voltage waveforms)	0.4†		∞ †	μs
Time interval from ϕ_1 clock to ϕ_2 clock input pulse, $t_{\phi 12}$ (See waveforms and Note 5)	0.01		10	μs
Time interval from ϕ_2 clock to ϕ_1 clock input pulse, $t_{\phi 21}$ (See waveforms and Note 5)	0.01		10	μs
Clock repetition rate	0		1	MHz

NOTES: 2. These voltage values are with respect to network ground terminal, V_{SS} .

3. Setup time is the interval immediately preceding the positive-going edge of the phase 1 clock during which period the data to be recognized must be maintained at the input to ensure its recognition.

4. Hold time is the interval immediately following the positive-going edge of the phase 1 clock during which period the data to be recognized must be maintained at the input to ensure its recognition.

5. The two clock pulses must never be simultaneously more than 3 volts more negative than V_{SS} .

† These values are at $V_{DD} = -14$ V, $V_{GG} = -28$ V, and $T_A = 25^\circ\text{C}$.

electrical characteristics over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	MIN	TYP†	MAX	UNITS
I_{IL} Logic 1 input current into data input	$V_i = -20$ V, $T^\circ = 25^\circ\text{C}$			0.5	μA
$I_{IL(\phi)}$ Logic 1 input current into either clock input	$V_i = -28$ V, $V_{GG} = 0$ V, $T^\circ = 25^\circ\text{C}$			50	μA
V_{OH} Logic 0 output voltage	$I_O = 0$ mA, $C_L = 20$ pF		0.3	-1	V
	$I_O = 2$ mA, $C_L = 20$ pF		-2.6	-5	V
	$I_O = 0$ mA, $V_{dd} = -12$ V, $V_{gg} = -24$ V		-0.5	-1	V
V_{OL} Logic 1 output voltage	$I_O = 0$, $C_L = 20$ pF	-12	-13.5	-14	V
	$I_O = 0.5$ mA	-10.5	-12.5	-14	V
	$I_O = 0$ mA, $V_{dd} = -12$ V, $V_{gg} = -24$ V, $V_{\phi}, V_{\phi L} = -24$ V, $C_L = 20$ pF, $V_{in(1)} = -8.5$ V, $V_{in(0)} = -2$ V	-8.8	-10.5	-12	V
R_{OH} Output resistance, logic 0	$I_O = -2.0$ mA		1.5	2.5	k Ω
R_{OL} Output resistance, logic 1	$I_O = 0.5$ mA		1.5	7	k Ω
I_{DD} Supply current from V_{DD} terminal*	TMS 3000 LR, $T^\circ = 25^\circ\text{C}$		-14	-20	mA
	TMS 3001 LR, $T^\circ = 25^\circ\text{C}$		-16	-24	mA
I_{GG} Supply current from V_{GG} terminal*	TMS 3000 LR, $T^\circ = 25^\circ\text{C}$		-2	-3.5	mA
	TMS 3001 LR, $T^\circ = 25^\circ\text{C}$		-2	-3.5	mA
f_{max} Maximum clock frequency		1			MHz

† Unless otherwise noted, voltages are as shown in the nominal column of the recommended operating conditions (nominal operating voltages).

† All typical values are at $T_A = 25^\circ\text{C}$.

* Current into a terminal is a positive value.

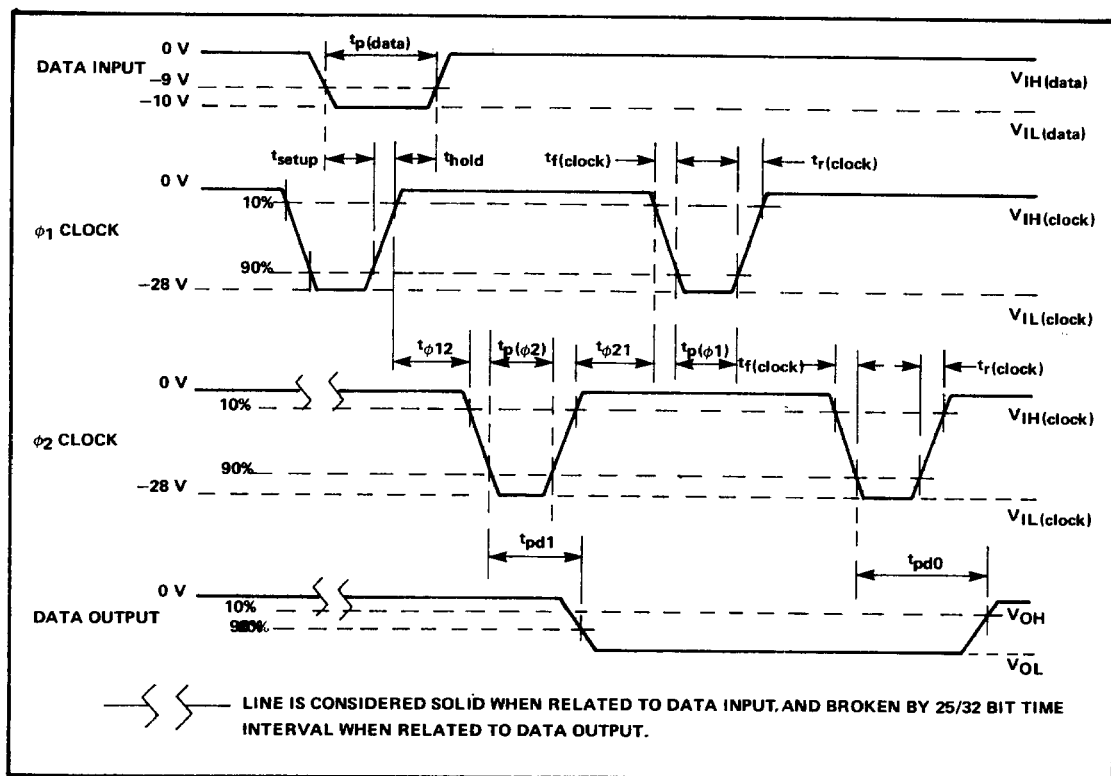
TMS 3000 LR-DUAL 25-BIT STATIC SHIFT REGISTER TMS 3001 LR-DUAL 32-BIT STATIC SHIFT REGISTER

switching characteristics, $V_{DD} = -14\text{ V}$, $V_{GG} = -28\text{ V}$, $R_L = 10\text{ m}\Omega$, $C_L = 20\text{ pF}$, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
t_{pd0} Propagation delay time to high level from ϕ_2 clock to data output	See voltage waveforms		325	475	ns
t_{pd1} Propagation delay time to low level from ϕ_2 clock to data output	See voltage waveforms		325	475	ns
$C_{in(\phi_1)}$ Capacitance of ϕ_1 clock input	$V_I = 0\text{ V}$, $V_{I(\phi_2)} = 0\text{ V}$, $f = 1\text{ MHz}$	TMS 3000 LR	8	12	pF
		TMS 3001 LR	11	15	pF
$C_{in(\phi_2)}$ Capacitance of ϕ_2 clock input*	$V_I = 0\text{ V}$, $V_{I(\phi_1)} = 0\text{ V}$, $f = 1\text{ MHz}$	TMS 3000 LR	15	20	pF
		TMS 3001 LR	20	30	pF
C_{in} Capacitance of data input	$V_I = 0$, $f = 1\text{ MHz}$		5	7	pF

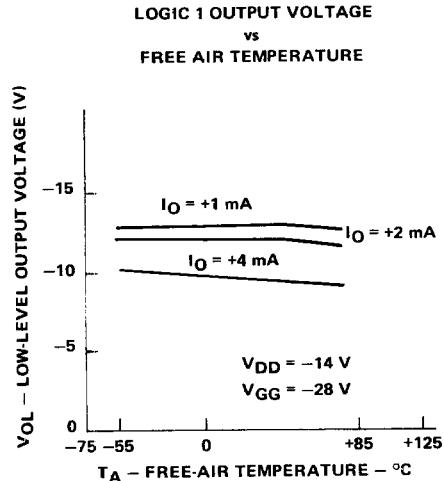
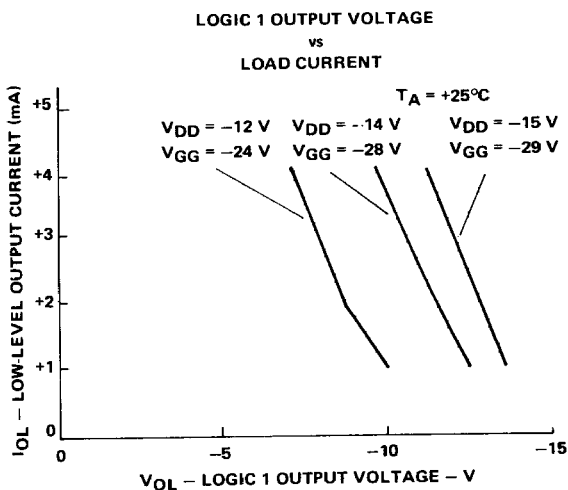
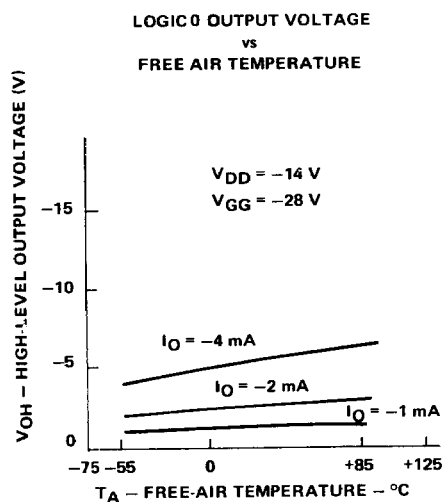
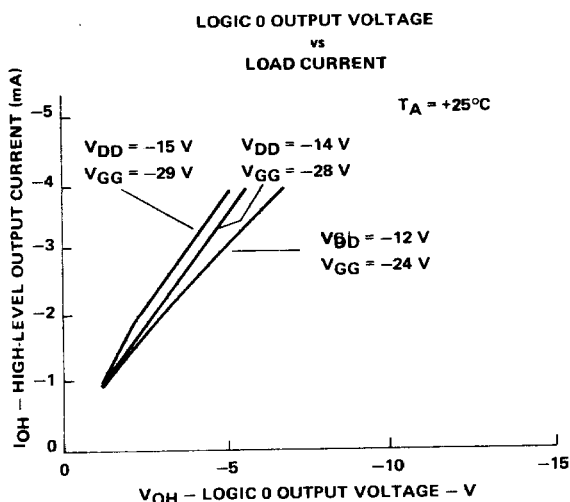
* $C_{in(\phi_2)}$ includes the capacitance of the internal ϕ_2' clock.

voltage waveforms



TMS 3000 LR-DUAL 25-BIT STATIC SHIFT REGISTER TMS 3001 LR-DUAL 32-BIT STATIC SHIFT REGISTER

typical characteristics



typical application data

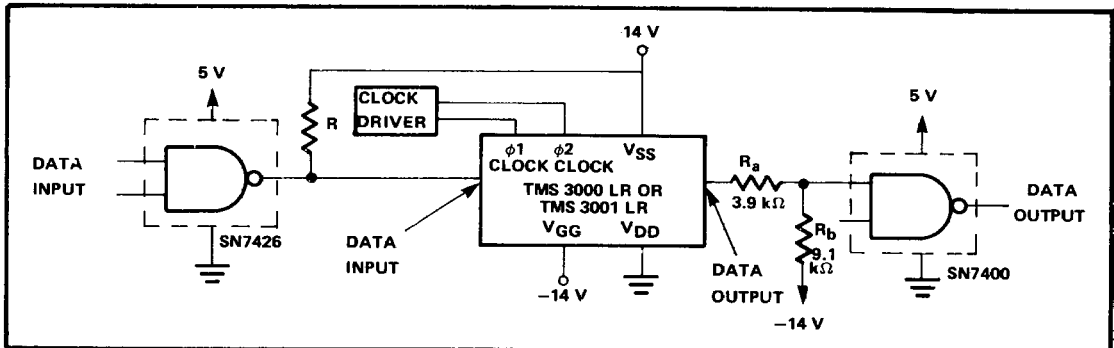
1) MOS/TTL interface

With proper supply voltages, interfacing can be achieved with only three resistors. A typical MOS/TTL interface is shown below.

An input pull-up resistor is required to provide the necessary input voltage swing. The value of this resistor (R) depends on the actual circuit requirements — values as low as $1\text{ k}\Omega$ can be used for high-speed operation, while values as high as $15\text{ k}\Omega$ can be used when low power consumption is important rather than high-speed.

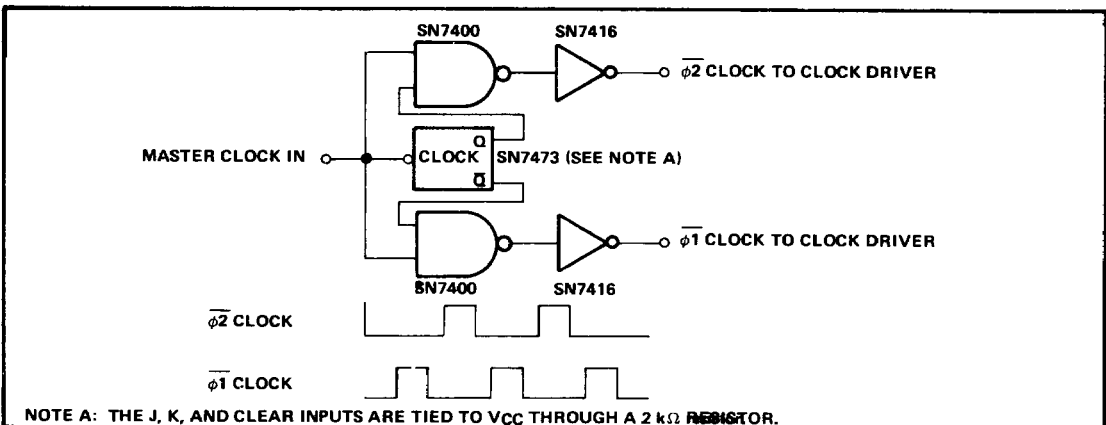
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typical application data (continued)



At the output interface, the 9.1-k Ω resistor sinks the 1.6 mA of TTL gate current when 0 volts is required on the TTL input. When 3 volts is required on the TTL input, the MOS output device supplies current from 14 volts, through the 3.9-k Ω resistor and the 9.1-k Ω resistor, to -14 volts. The 3.9-k Ω resistor limits the voltage at the TTL gate input to 5 volts maximum.

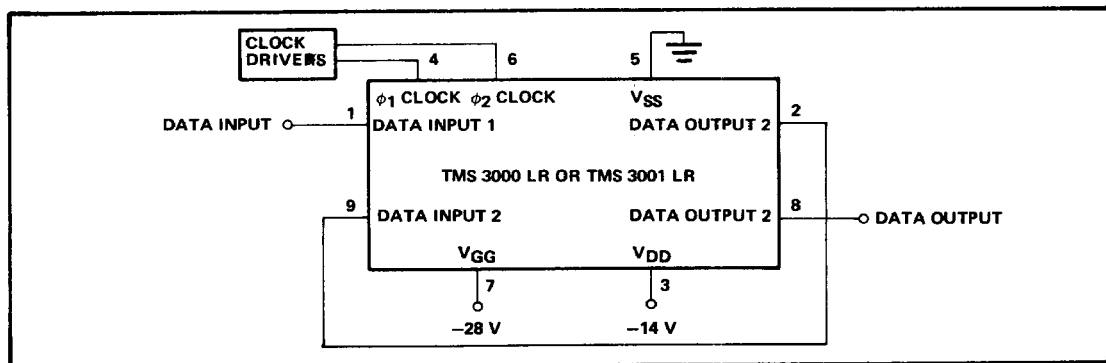
2) Two-phase clock generator



TMS 3000 LR-DUAL 25-BIT STATIC SHIFT REGISTER

TMS 3001 LR-DUAL 32-BIT STATIC SHIFT REGISTER

expansion to single 50- or 64-bit register



schematic (each register)

